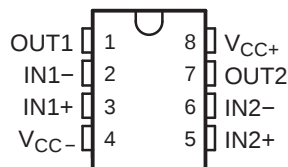


FEATURES

- Dual-Supply Operation . . . ± 5 V to ± 18 V
- Low Noise Voltage . . . $4.5 \text{ nV}/\sqrt{\text{Hz}}$
- Low Input Offset Voltage . . . 0.15 mV
- Low Total Harmonic Distortion . . . 0.002%
- High Slew Rate . . . $7 \text{ V}/\mu\text{s}$
- High-Gain Bandwidth Product . . . 16 MHz
- High Open-Loop AC Gain . . . 800 at 20 kHz
- Large Output-Voltage Swing . . . 14.1 V to -14.6 V
- Excellent Gain and Phase Margins

D (SOIC), DGK (MSOP), OR P (PDIP) PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The MC33078 is a bipolar dual operational amplifier with high-performance specifications for use in quality audio and data-signal applications. This device operates over a wide range of single- and dual-supply voltages and offers low noise, high-gain bandwidth, and high slew rate. Additional features include low total harmonic distortion, excellent phase and gain margins, large output voltage swing with no deadband crossover distortion, and symmetrical sink/source performance.

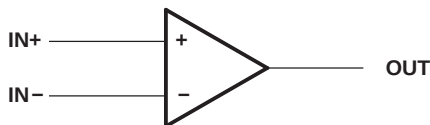
ORDERING INFORMATION

T_A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
-40°C to 85°C	PDIP – P	Tube of 50	MC33078P	MC33078P
	SOIC – D	Tube of 75	MC33078D	M33078
		Reel of 2500	MC33078DR	
	VSSOP/MSOP – DGK	Reel of 2500	MC33078DGKR	MY_
		Reel of 250	MC33078DGKT	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DGK: The actual top-side marking has one additional character that designates the assembly/test site.

SYMBOL (EACH AMPLIFIER)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC+}	Supply voltage ⁽²⁾		18	V
V _{CC-}	Supply voltage ⁽²⁾		-18	V
V _{CC+} - V _{CC-}	Supply voltage		36	V
	Input voltage, either input ⁽²⁾⁽³⁾		V _{CC+} or V _{CC-}	V
	Input current ⁽⁴⁾		±10	mA
	Duration of output short circuit ⁽⁵⁾		Unlimited	
θ _{JA}	Package thermal impedance, junction to free air ⁽⁶⁾⁽⁷⁾	D package	97	°C/W
		DGK package	172	
		P package	85	
T _J	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
- (3) The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
- (4) Excessive input current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
- (5) The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
- (6) Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_{J(max)} - T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

		MIN	MAX	UNIT
V _{CC-}	Supply voltage	-5	-18	V
V _{CC+}		5	18	
T _A	Operating free-air temperature range	-40	85	°C

Electrical Characteristics

$V_{CC-} = -15\text{ V}$, $V_{CC+} = 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

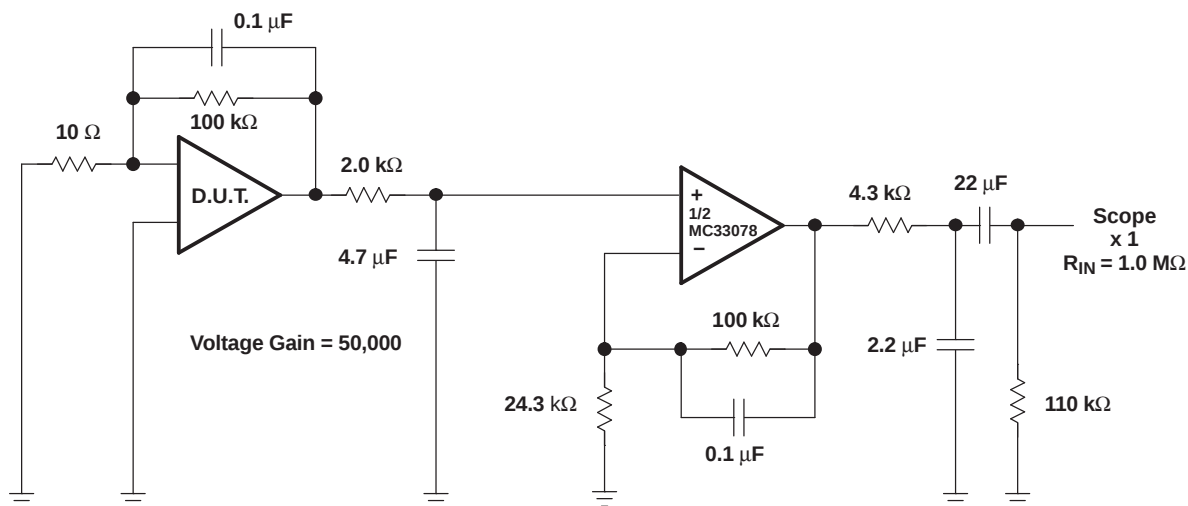
PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
V _{IO}	Input offset voltage	V _O = 0, R _S = 10 Ω, V _{CM} = 0		0.15		2	mV	
						3		
αV _{IO}	Input offset voltage temperature coefficient	V _O = 0, R _S = 10 Ω, V _{CM} = 0		T _A = −40°C to 85°C		2	μV/°C	
I _{IB}	Input bias current	V _O = 0, V _{CM} = 0		T _A = 25°C		300	750	nA
				T _A = −40°C to 85°C		800		
I _{IO}	Input offset current	V _O = 0, V _{CM} = 0		T _A = 25°C		25	150	nA
				T _A = −40°C to 85°C		175		
V _{ICR}	Common-mode input voltage range	ΔV _{IO} = 5 mV, V _O = 0			±13	±14		V
A _{VD}	Large-signal differential voltage amplification	R _L ≥ 2 kΩ, V _O = ±10 V		T _A = 25°C		90	110	dB
				T _A = −40°C to 85°C		85		
V _{OM}	Maximum output voltage swing	V _{ID} = ±1 V	R _L = 600 Ω	V _{OM+}	10.7		V	
				V _{OM−}	−11.9			
			R _L = 2k Ω	V _{OM+}	13.2	13.8		
				V _{OM−}	−13.2	−13.7		
			R _L = 10k Ω	V _{OM+}	13.5	14.1		
				V _{OM−}	−14	−14.6		
CMMR	Common-mode rejection ratio	V _{IN} = ±13 V			80	100	dB	
k _{SVR} ⁽¹⁾	Supply-voltage rejection ratio	V _{CC+} = 5 V to 15 V, V _{CC−} = −5 V to −15 V			80	105	dB	
I _{OS}	Output short-circuit current	V _{ID} = 1 V, Output to GND		Source current		15	29	mA
				Sink current		−20	−37	
I _{CC}	Supply current (per channel)	V _O = 0		T _A = 25°C		2.05	2.5	mA
				T _A = −40°C to 85°C		2.75		

(1) Measured with $V_{CC\pm}$ differentially varied at the same time

Operating Characteristics

$V_{CC-} = -15\text{ V}$, $V_{CC+} = 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$A_{VD} = 1$, $V_{IN} = -10\text{ V}$ to 10 V , $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		5	7		V/ μs
GBW	Gain bandwidth product	$f = 100\text{ kHz}$		10	16		MHz
B_1	Unity gain frequency	Open loop			9		MHz
G_m	Gain margin	$R_L = 2\text{ k}\Omega$	$C_L = 0\text{ pF}$		-11		dB
			$C_L = 100\text{ pF}$		-6		
Φ_m	Phase margin	$R_L = 2\text{ k}\Omega$	$C_L = 0\text{ pF}$		55		deg
			$C_L = 100\text{ pF}$		40		
	Amp-to-amp isolation	$f = 20\text{ Hz}$ to 20 kHz			-120		dB
	Power bandwidth	$V_O = 27\text{ V}_{(PP)}$, $R_L = 2\text{ k}\Omega$, THD $\leq 1\%$			120		kHz
THD	Total harmonic distortion	$V_O = 3\text{ V}_{rms}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega$, $f = 20\text{ Hz}$ to 20 kHz			0.002		%
Z_o	Open-loop output impedance	$V_O = 0$, $f = 9\text{ MHz}$			37		Ω
r_{id}	Differential input resistance	$V_{CM} = 0$			175		k Ω
C_{id}	Differential input capacitance	$V_{CM} = 0$			12		pF
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 100\ \Omega$			4.5		nV/ $\sqrt{\text{Hz}}$
I_n	Equivalent input noise current	$f = 1\text{ kHz}$			0.5		pA/ $\sqrt{\text{Hz}}$

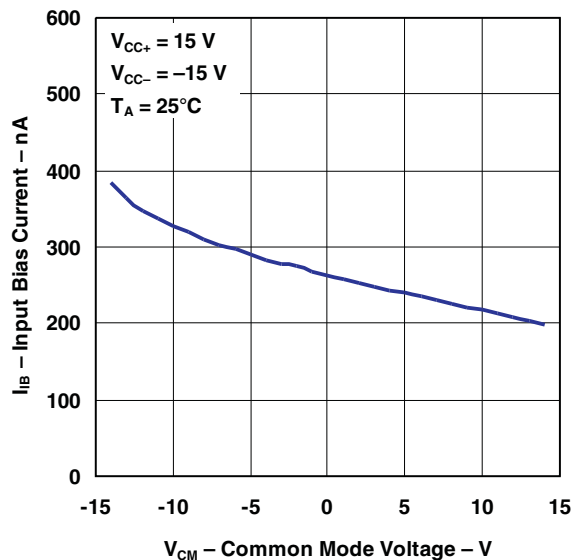


NOTE: All capacitors are non-polarized.

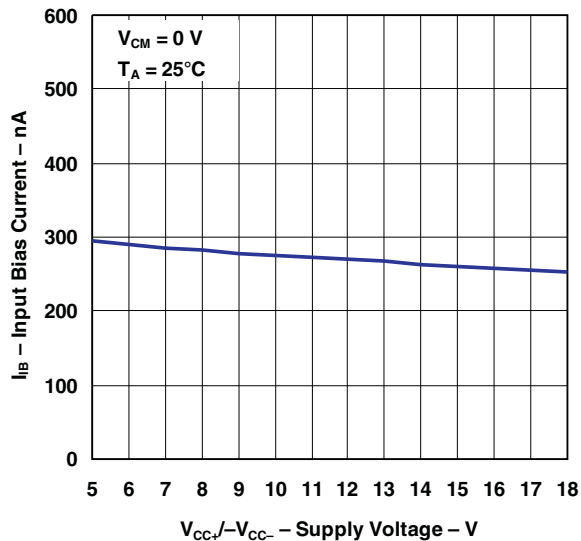
Figure 1. Voltage Noise Test Circuit (0.1 Hz to 10 Hz)

TYPICAL CHARACTERISTICS

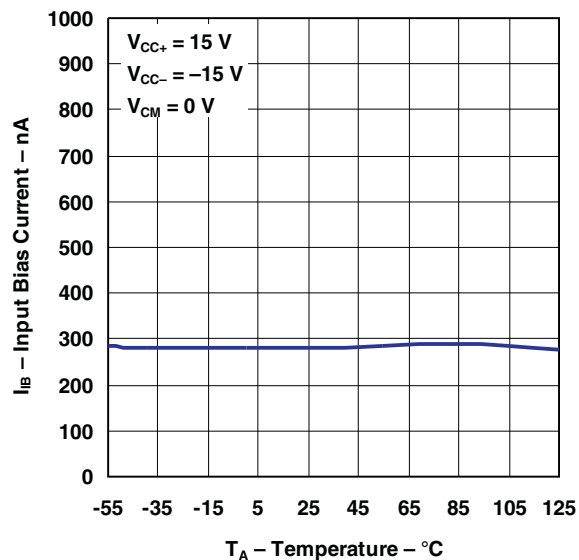
INPUT BIAS CURRENT
VS
COMMON-MODE VOLTAGE



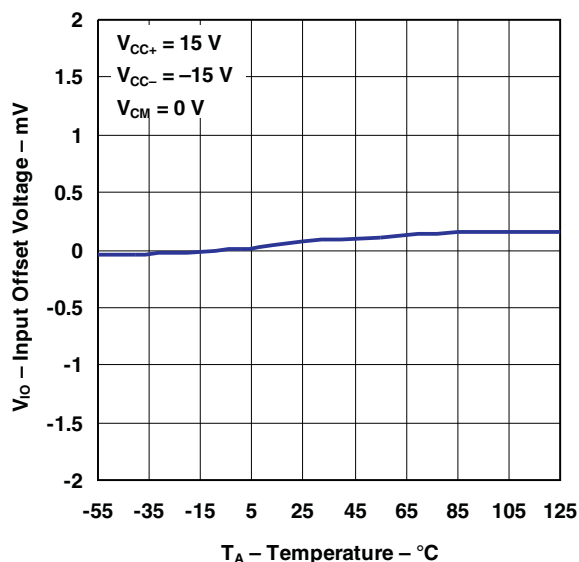
INPUT BIAS CURRENT
VS
SUPPLY VOLTAGE



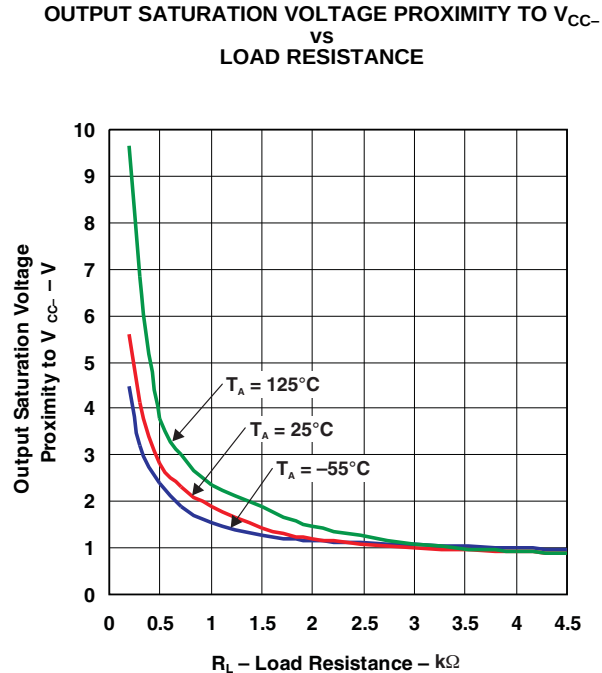
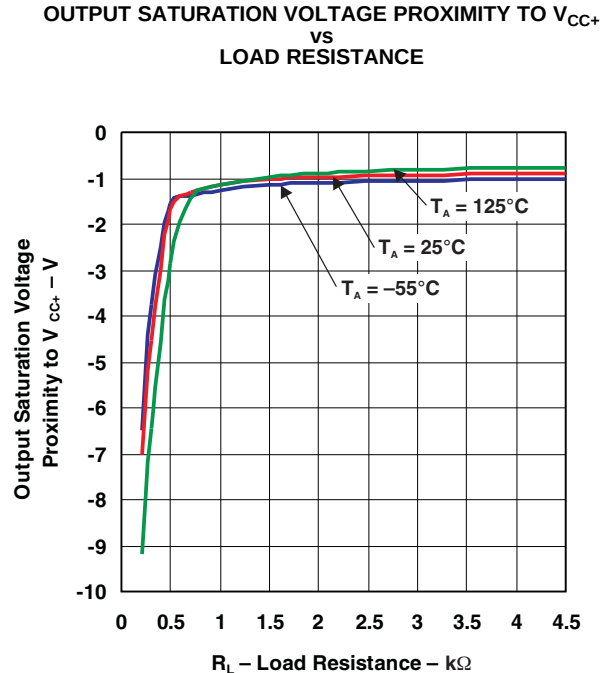
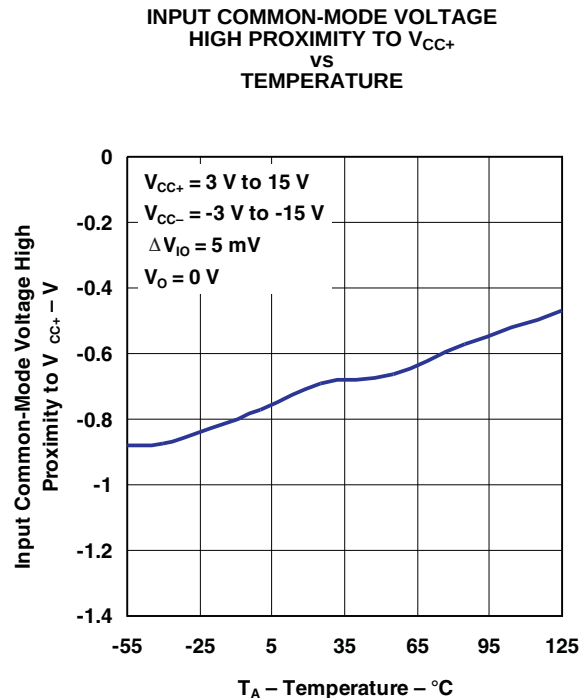
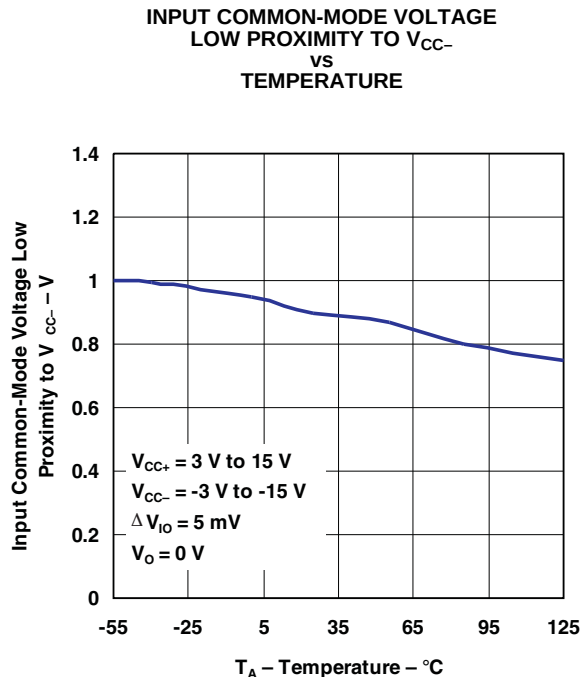
INPUT BIAS CURRENT
VS
TEMPERATURE



INPUT OFFSET VOLTAGE
VS
TEMPERATURE

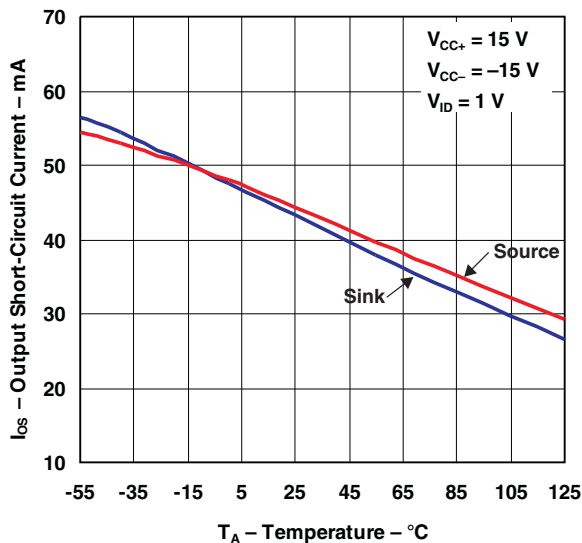


TYPICAL CHARACTERISTICS (continued)

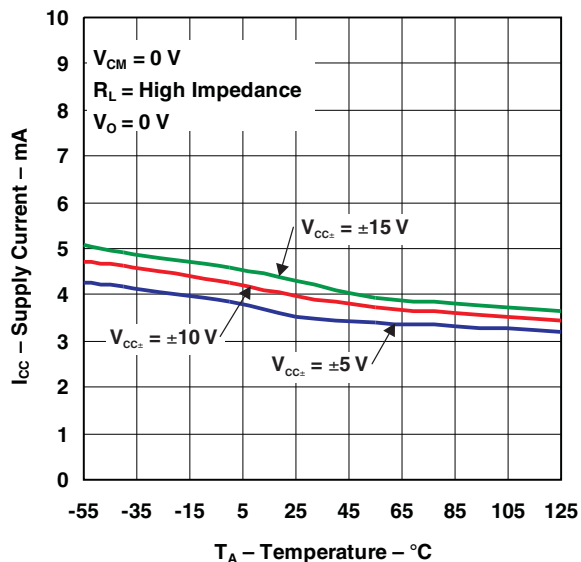


TYPICAL CHARACTERISTICS (continued)

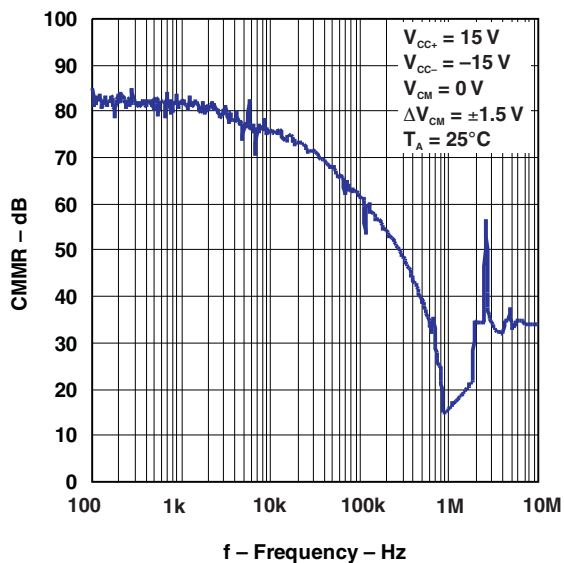
OUTPUT SHORT-CIRCUIT CURRENT
VS
TEMPERATURE



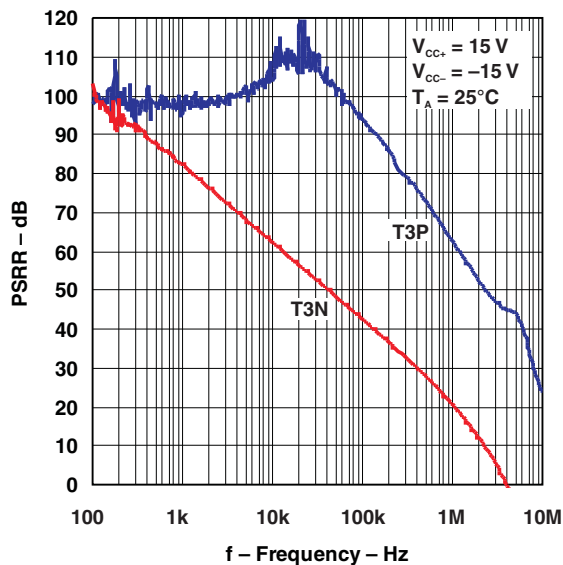
SUPPLY CURRENT
VS
TEMPERATURE



CMRR
VS
FREQUENCY

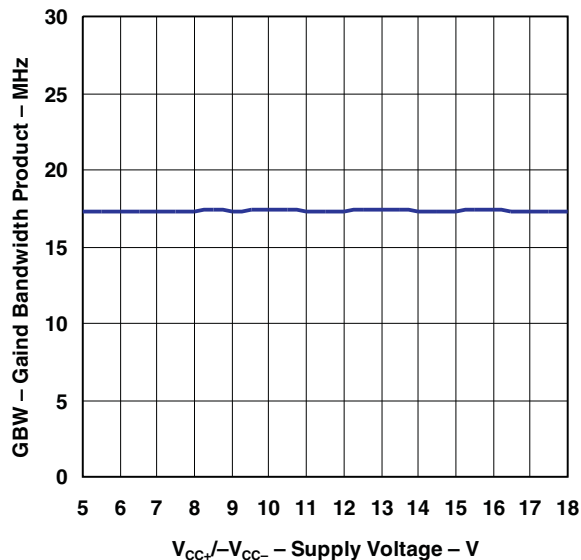


PSSR
VS
FREQUENCY

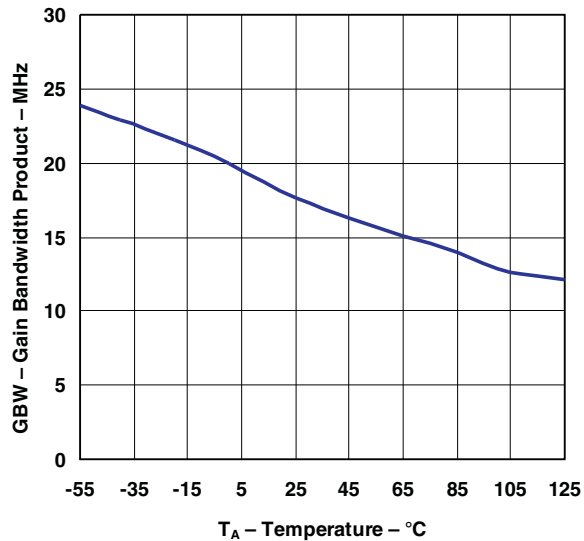


TYPICAL CHARACTERISTICS (continued)

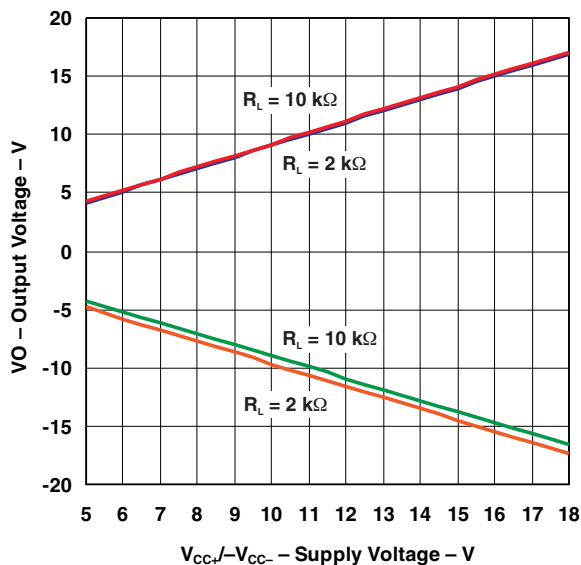
GAIN BANDWIDTH PRODUCT
vs
SUPPLY VOLTAGE



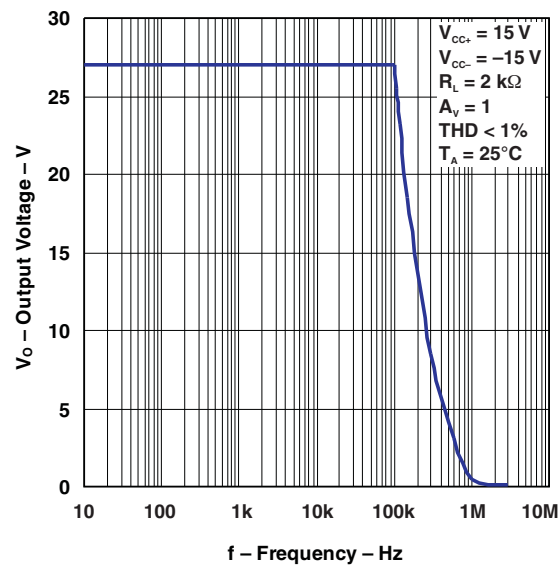
GAIN BANDWIDTH PRODUCT
vs
TEMPERATURE



OUTPUT VOLTAGE
vs
SUPPLY VOLTAGE

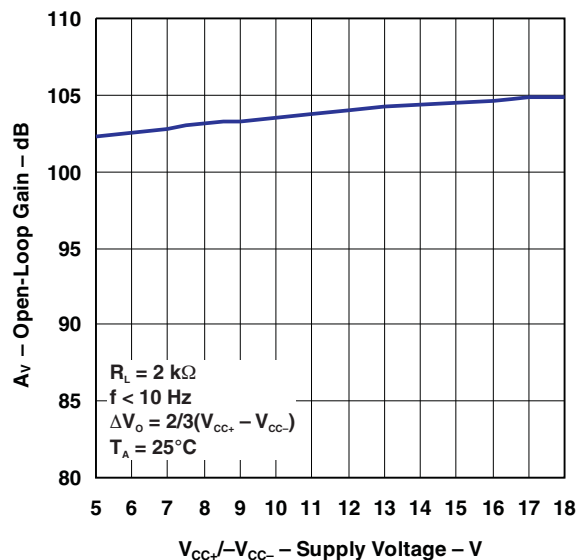


OUTPUT VOLTAGE
vs
FREQUENCY

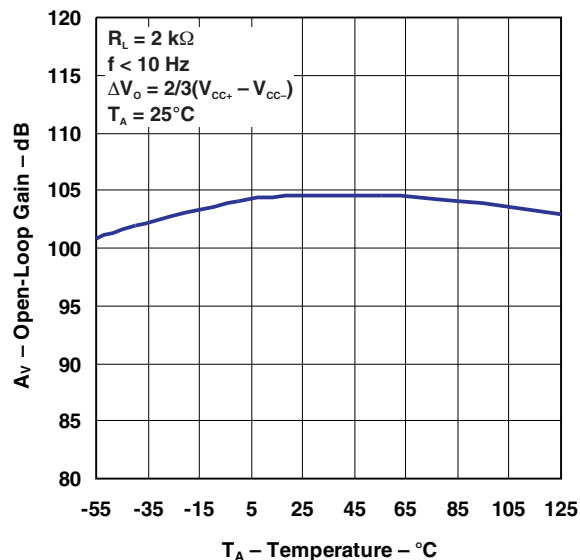


TYPICAL CHARACTERISTICS (continued)

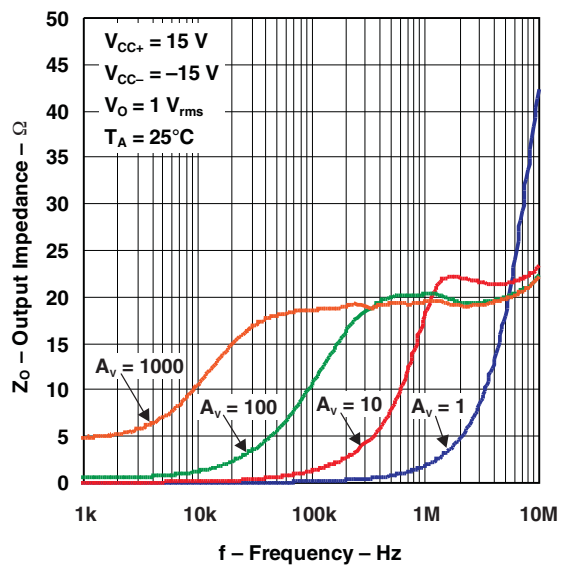
OPEN-LOOP GAIN
vs
SUPPLY VOLTAGE



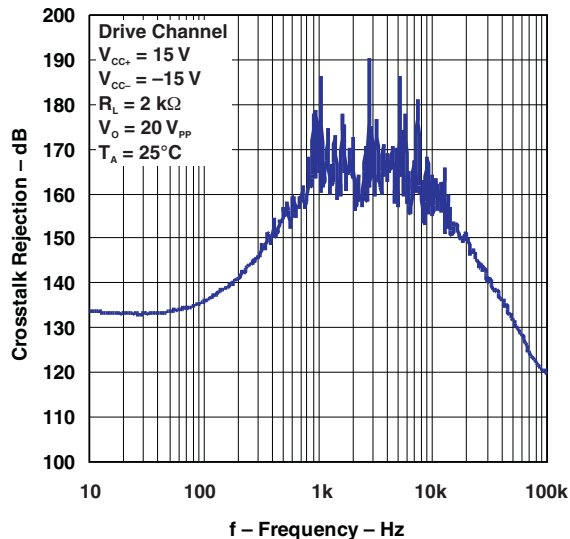
OPEN-LOOP GAIN
vs
TEMPERATURE



OUTPUT IMPEDANCE
vs
FREQUENCY

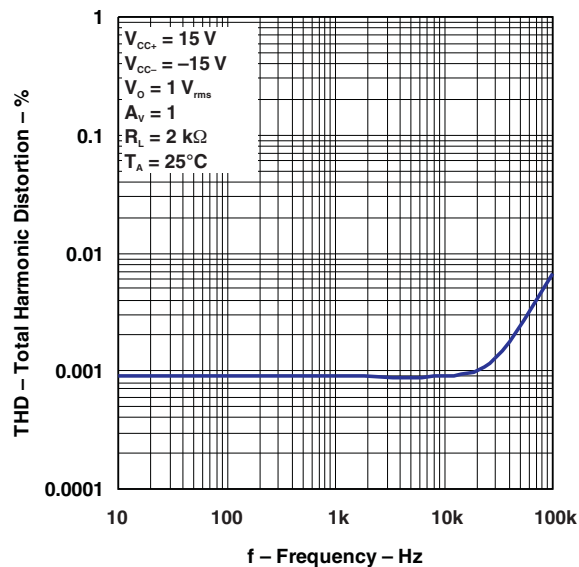


CROSSTALK REJECTION
vs
FREQUENCY

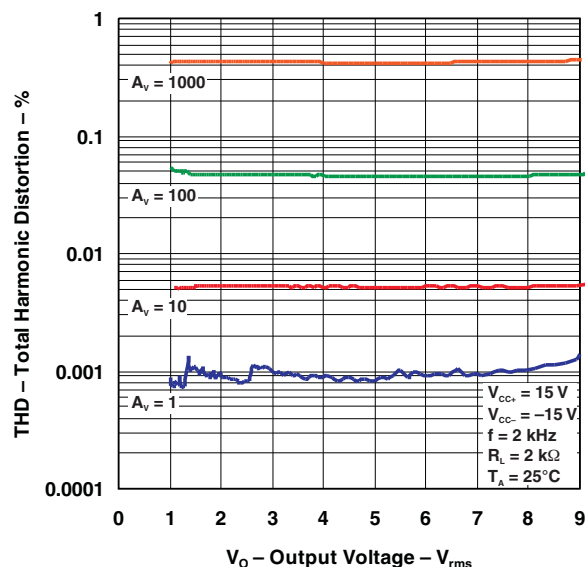


TYPICAL CHARACTERISTICS (continued)

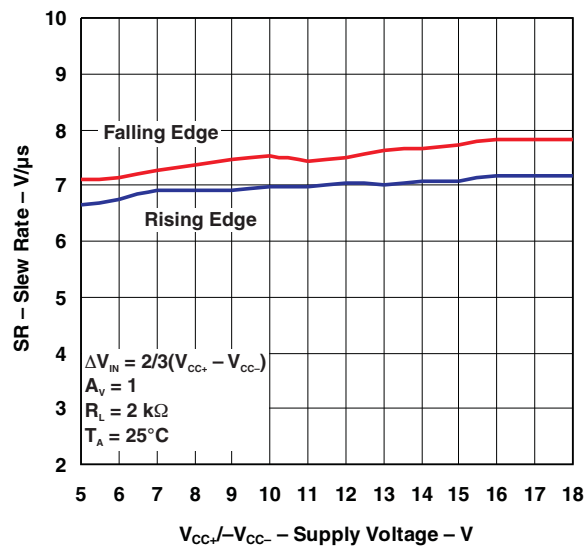
TOTAL HARMONIC DISTORTION
VS
FREQUENCY



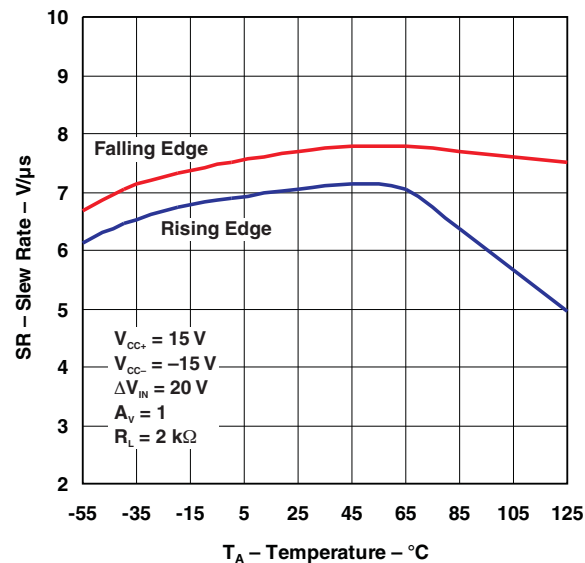
TOTAL HARMONIC DISTORTION
VS
OUTPUT VOLTAGE



SLEW RATE
VS
SUPPLY VOLTAGE

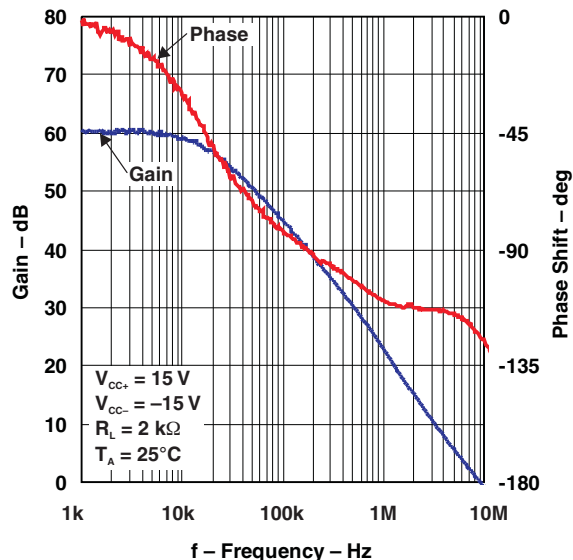


SLEW RATE
VS
TEMPERATURE

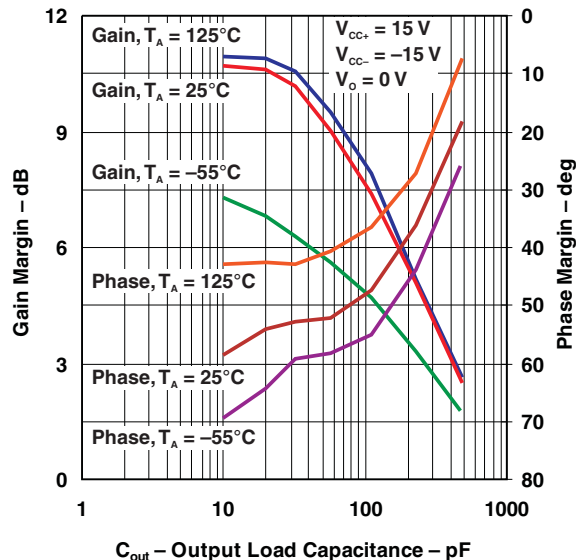


TYPICAL CHARACTERISTICS (continued)

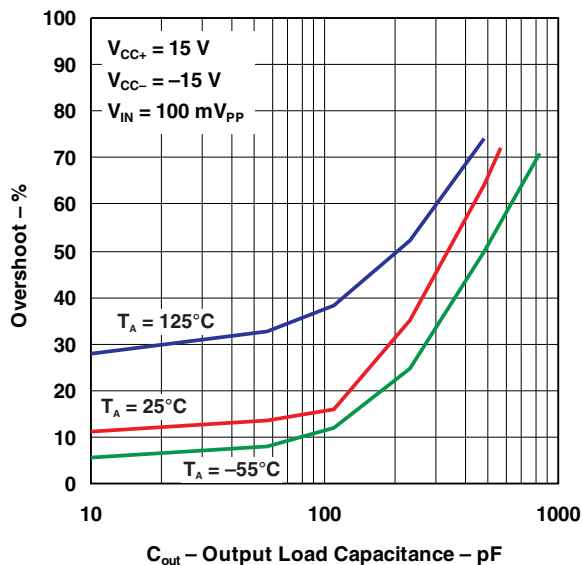
GAIN AND PHASE
VS
FREQUENCY



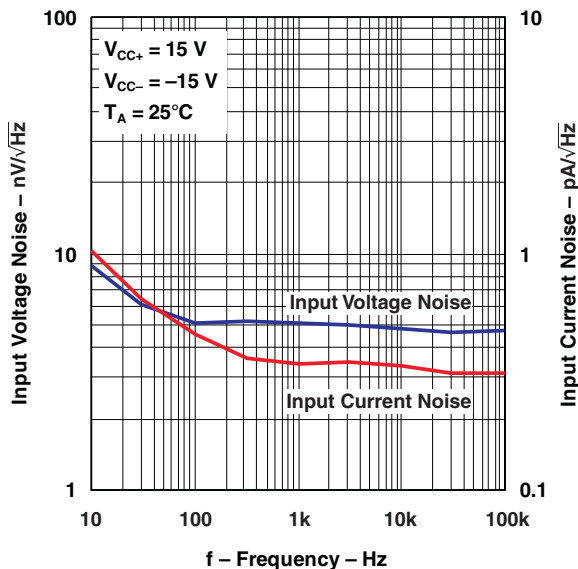
GAIN AND PHASE MARGIN
VS
OUTPUT LOAD CAPACITANCE



OVERSHOOT
VS
OUTPUT LOAD CAPACITANCE

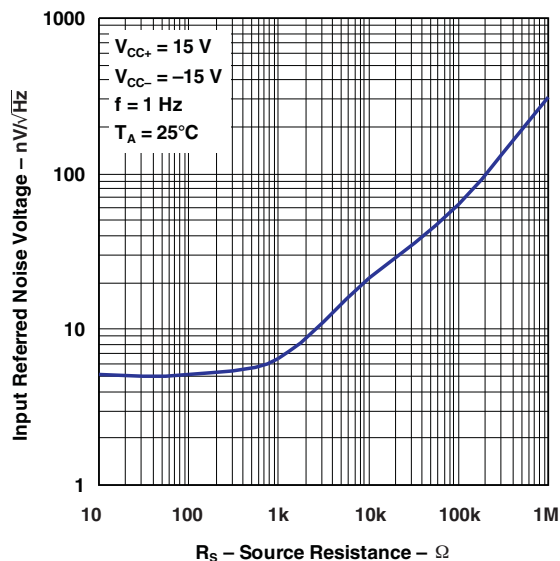


INPUT VOLTAGE AND CURRENT NOISE
VS
FREQUENCY

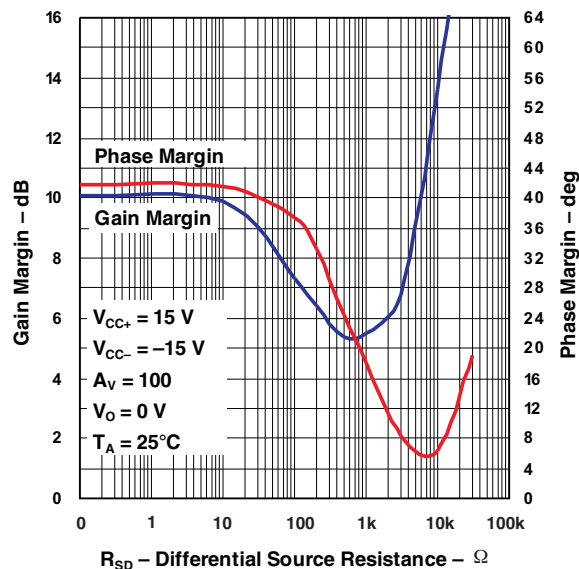


TYPICAL CHARACTERISTICS (continued)

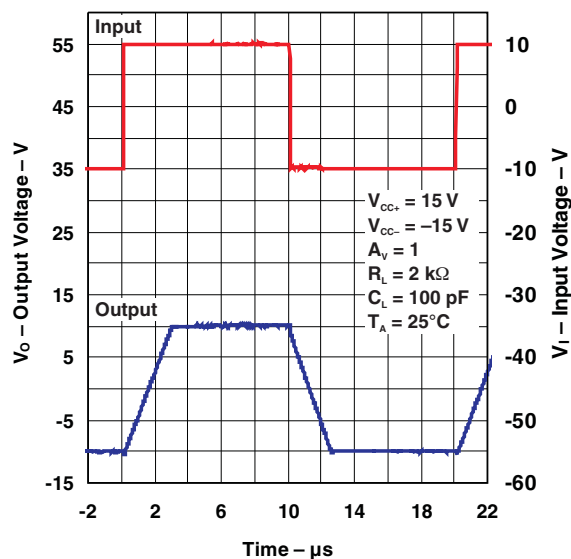
INPUT REFERRED NOISE VOLTAGE
vs
SOURCE RESISTANCE



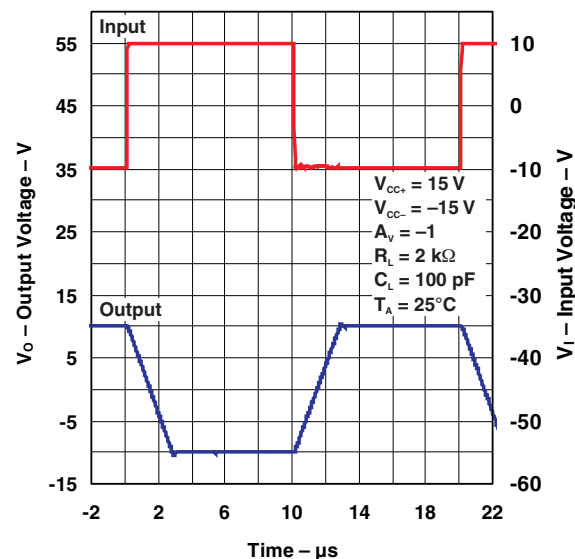
GAIN AND PHASE MARGIN
vs
DIFFERENTIAL SOURCE RESISTANCE



LARGE SIGNAL TRANSIENT RESPONSE
($A_V = 1$)

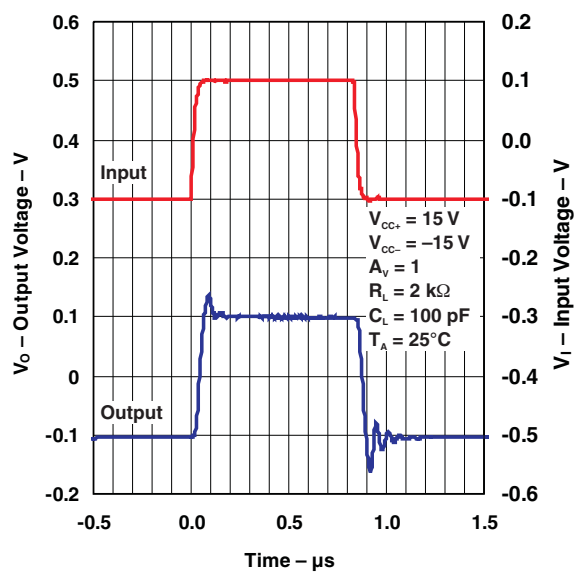


LARGE SIGNAL TRANSIENT RESPONSE
($A_V = -1$)

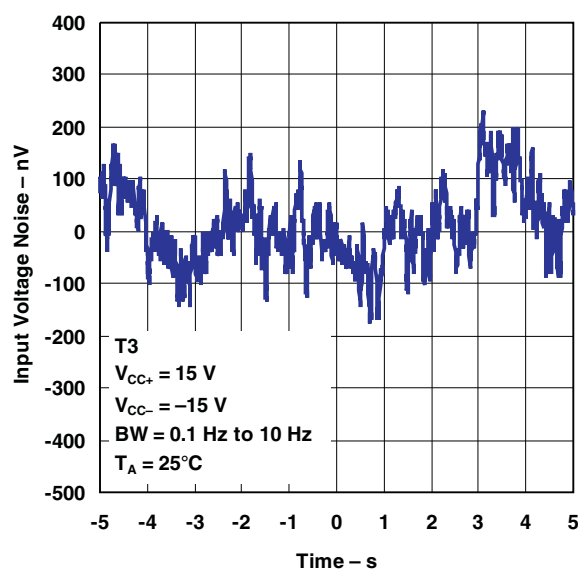


TYPICAL CHARACTERISTICS (continued)

SMALL SIGNAL TRANSIENT RESPONSE



LOW-FREQUENCY NOISE



APPLICATION INFORMATION

Output Characteristics

All operating characteristics are specified with 100-pF load capacitance. The MC33078 can drive higher capacitance loads. However, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or oscillation. The value of the load capacitance at which oscillation occurs varies from lot to lot. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem (see Figure 2).

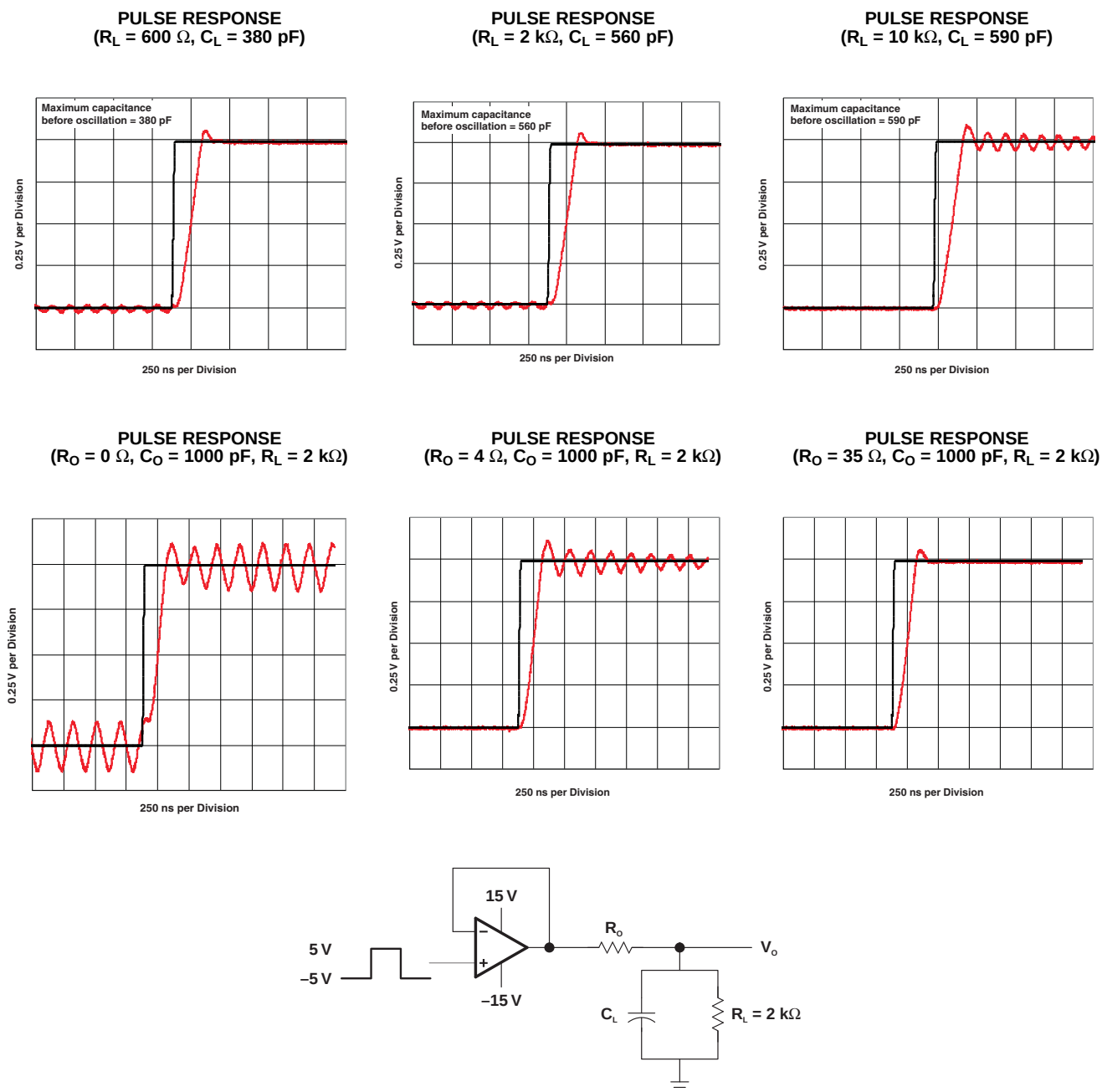


Figure 2. Output Characteristics

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
MC33078D	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	M33078
MC33078DGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MYU
MC33078DGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MYU
MC33078DGKR1G4	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MYU
MC33078DGKR1G4.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MYU
MC33078DGKT	Obsolete	Production	VSSOP (DGK) 8	-	-	Call TI	Call TI	-40 to 85	MYU
MC33078DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	M33078
MC33078DR-NG	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	M33078
MC33078DR-NG.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	M33078
MC33078DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	M33078
MC33078P	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	MC33078P
MC33078P.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	MC33078P

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MC33078DGKR	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
MC33078DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
MC33078DGKR1G4	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
MC33078DGKR1G4	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
MC33078DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
MC33078DR-NG	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
MC33078DR-NG	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

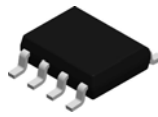
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MC33078DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
MC33078DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
MC33078DGKR1G4	VSSOP	DGK	8	2500	353.0	353.0	32.0
MC33078DGKR1G4	VSSOP	DGK	8	2500	353.0	353.0	32.0
MC33078DR	SOIC	D	8	2500	340.5	338.1	20.6
MC33078DR-NG	SOIC	D	8	2500	353.0	353.0	32.0
MC33078DR-NG	SOIC	D	8	2500	356.0	356.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
MC33078P	P	PDIP	8	50	506	13.97	11230	4.32
MC33078P.A	P	PDIP	8	50	506	13.97	11230	4.32

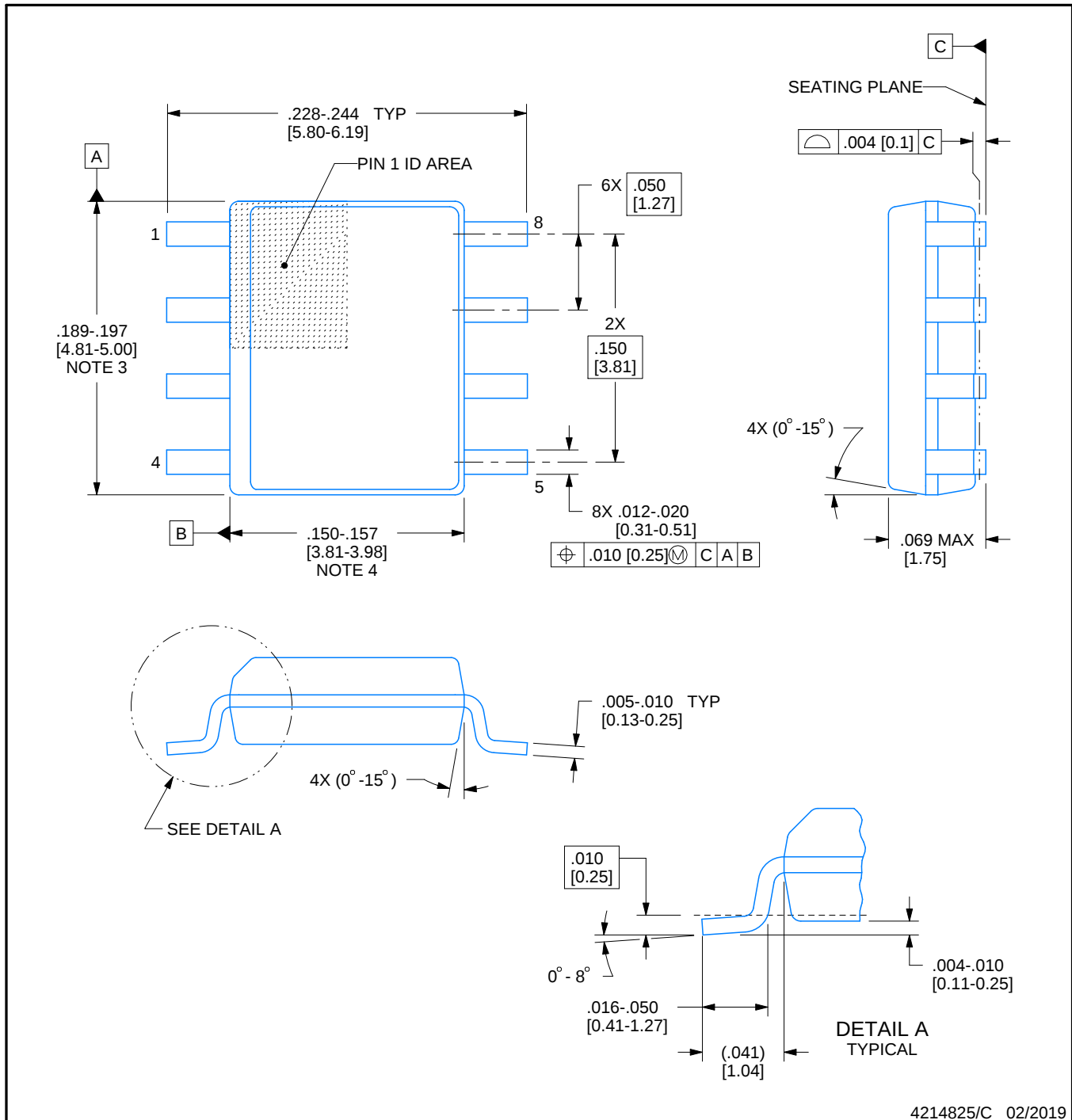


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

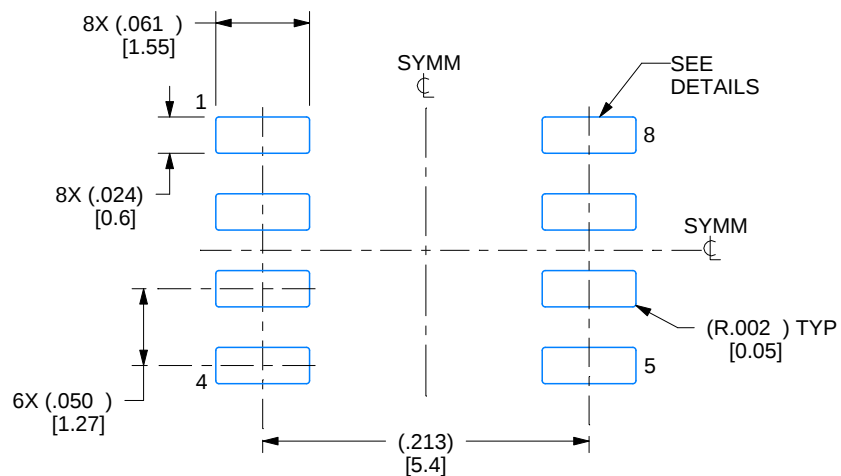
NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

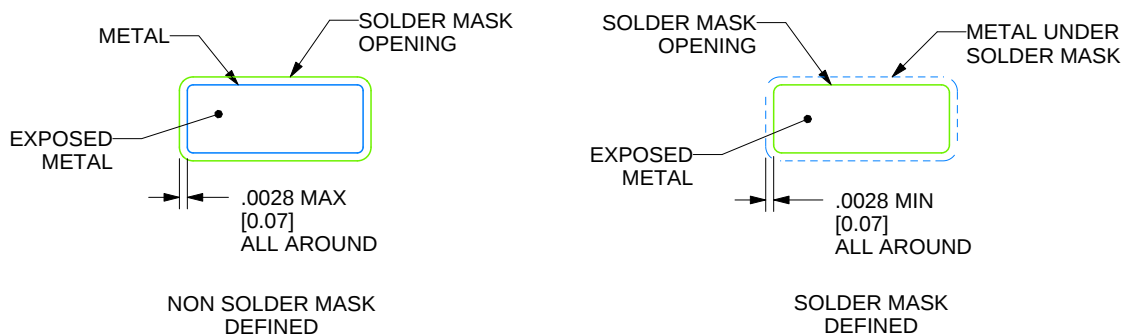
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

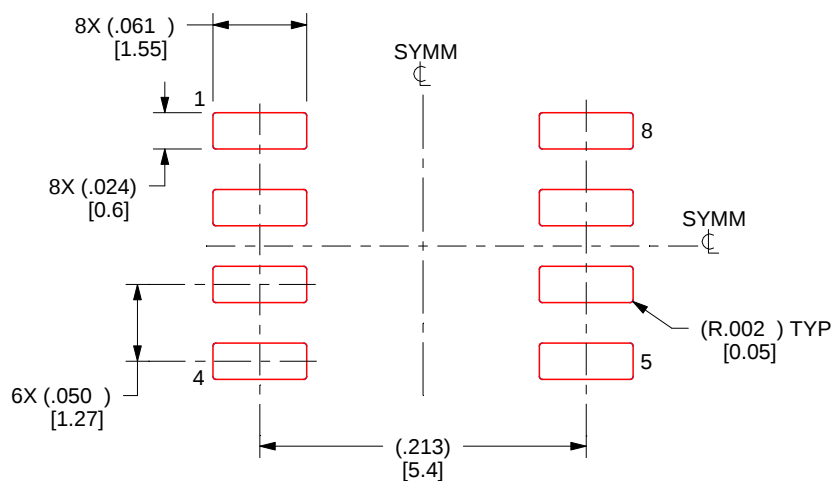
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

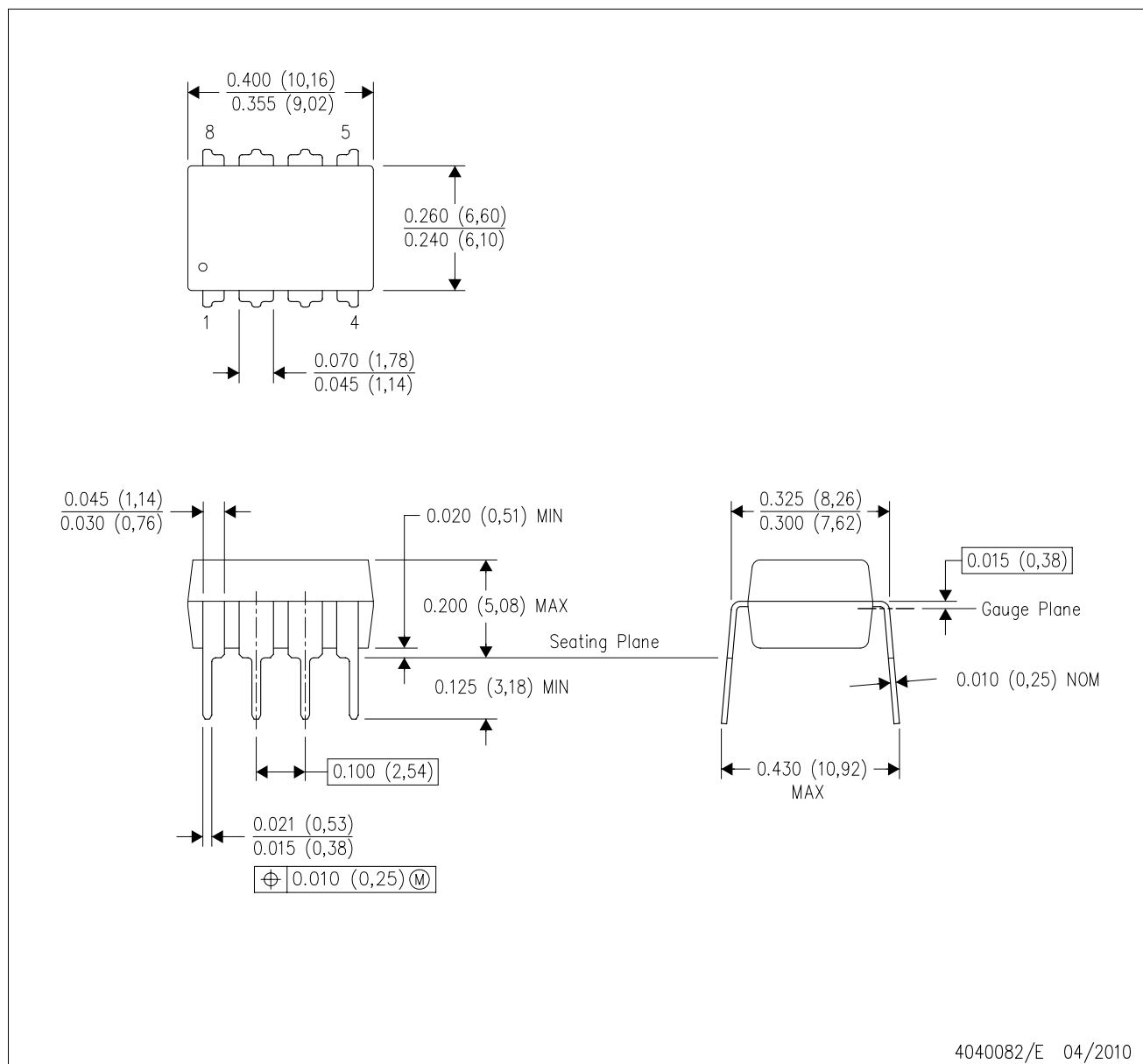
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

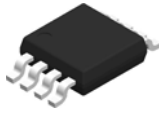
P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

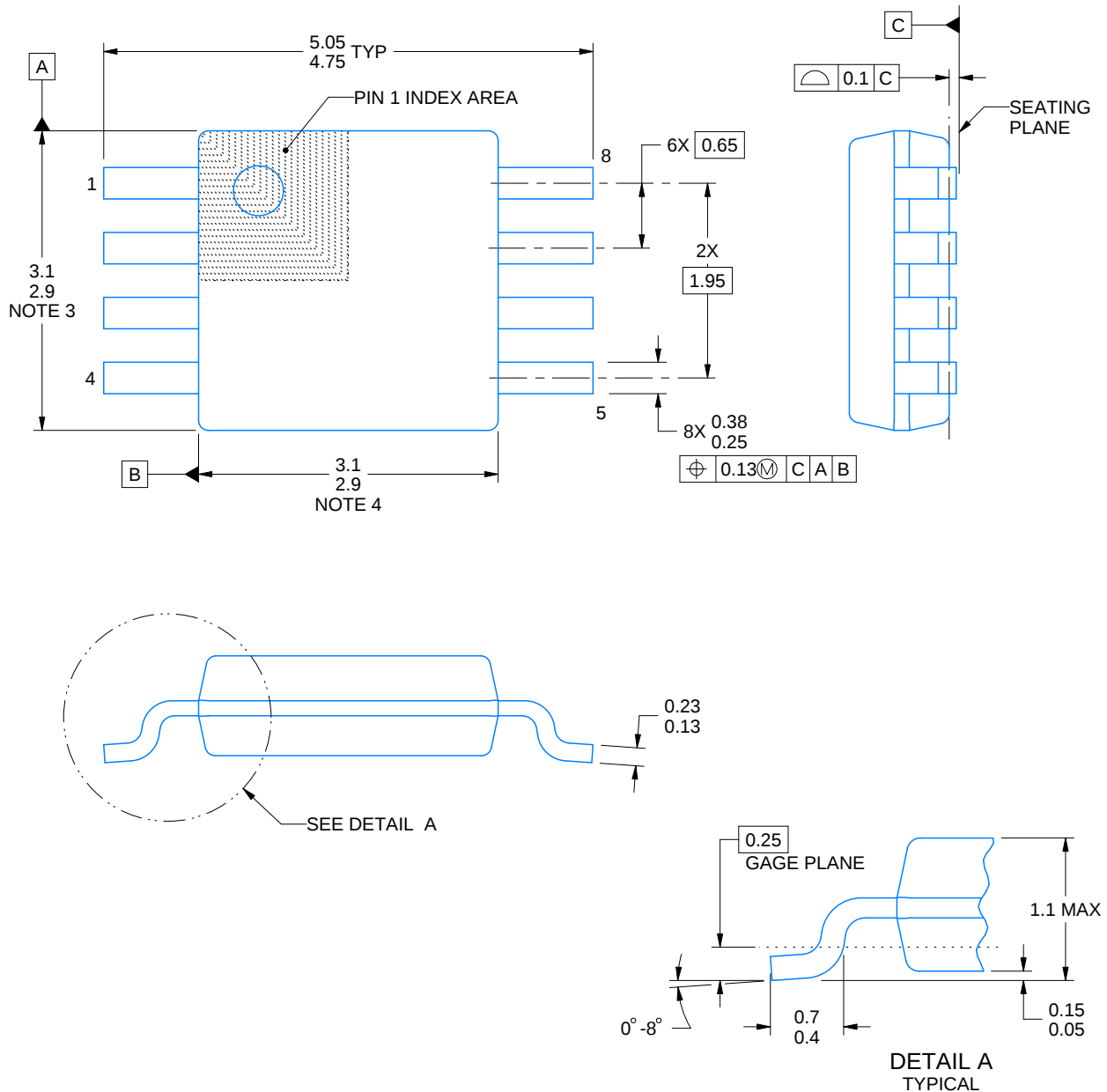
DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

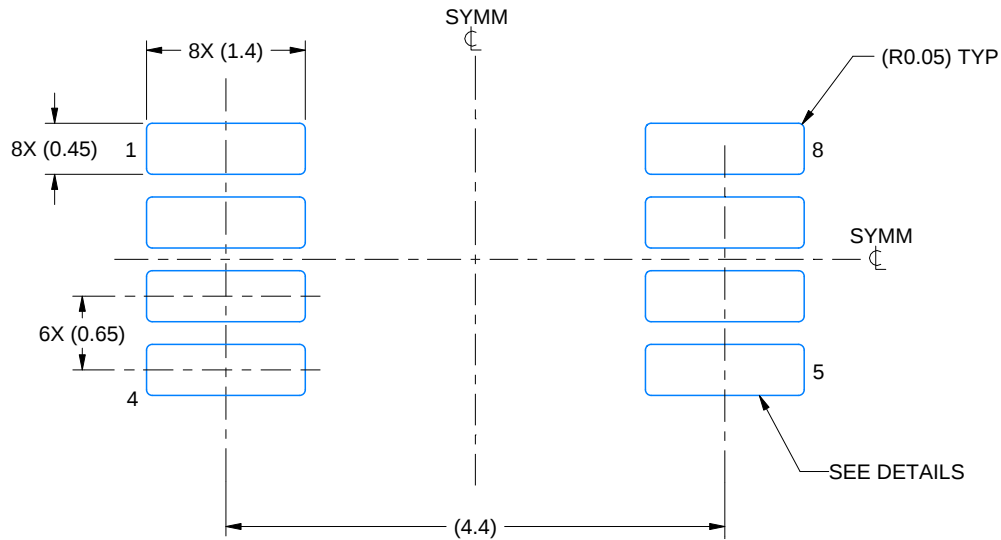
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

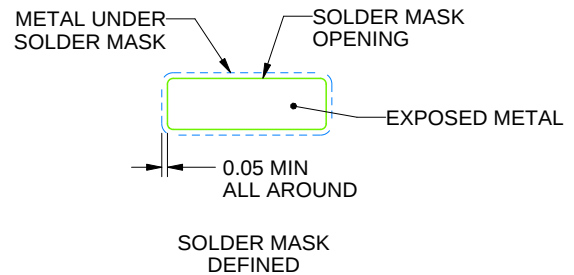
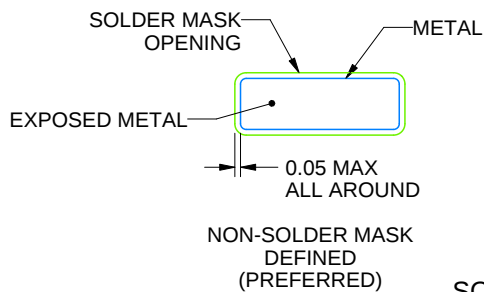
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

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NOTES: (continued)

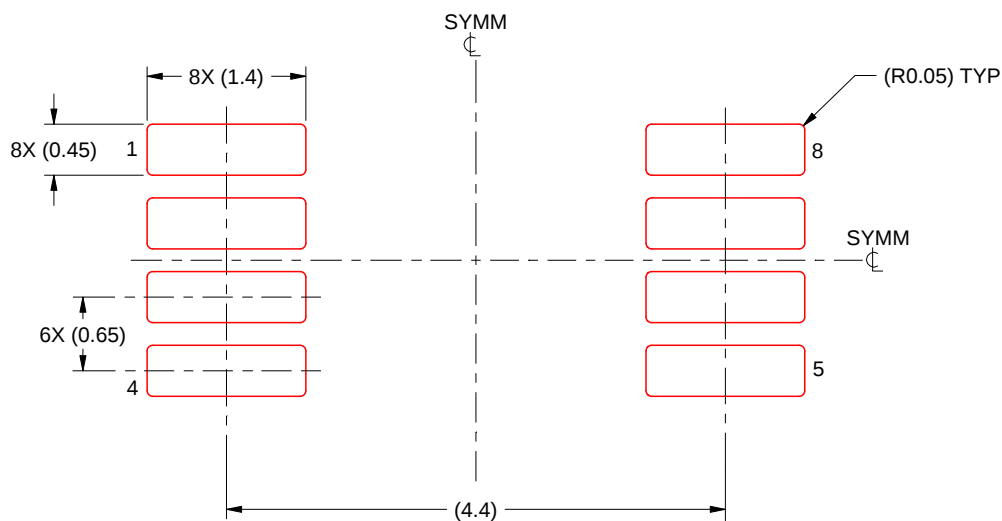
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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